- 1N5711 AVAILABLE IN JANHC AND JANKC PER MIL-PRF-19500/444
- 1N5712 AVAILABLE IN JANHC AND JANKC PER MIL-PRF-19500/445
- SCHOTTKY BARRIER DIODE CHIPS FOR GENERAL PURPOSE APPLICATION
- SILICON DIOXIDE PASSIVATED
- COMPATIBLE WITH ALL WIRE BONDING AND DIE ATTACH TECHNIQUES, WITH THE EXCEPTION OF SOLDER REFLOW

CD2810 CD5711 CD5712 CD6857 CD6858 CD6916

MAXIMUM RATINGS

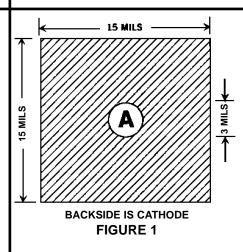
Operating Temperature: -55°C to +125°C Storage Temperature: -65°C to +150°C

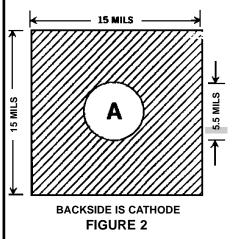
ELECTRICAL CHARACTERISTICS @ 25°C, unless otherwise specified

CDI TYPE NUMBER	MINIMUM BREAKDOWN VOLTAGE (2)	MAXIMUM FORWARD VOLTAGE	MAXIMUM FORWARD VOLTAGE	MAXIMUM REVERSE LEAKAGE CURRENT		MAXIMUM CAPACITANCE @ V = 0 VOLTS f = 1.0 MHz	FIGURE NUMBER
	V _{BR} @ 10 μ A	V _F @ 1 mA	V _{F @} I _F	1 _R @ V _R		c _T	
	VOLTS	VOLTS	VOLTS @ mA	nA	VOLTS	PICO FARADS	
CD2810	20	0.41	1.0 @ 35	100	15	1.2	1
CD5711	70	0.41	1.0 @15	200	50	2.0	2
CD5712	20	0.41	1.0 @ 35	150	16	1.2	1
CD6857	20	0.35	0.75 @ 35	150	16	4.5	2
CD6858	70	0.36	0.65 @ 15	200	50	4.5	2
			0.27 @ 0.1	100	1		
CD6916	40	0.34	0.34 @ 1.0	200	20	5	2
	(2)		0.47 @ 10.0	500	40		

NOTES: (1) Effective Minority Carrier Lifetime (τ) is 100 Pico Seconds

(2) CD6916 V _{BR} measured @ 500 nanoamps





DESIGN DATA

METALLIZATION: Top: (Anode) Back: (Cathode)	
AL THICKNESS 25,000 Å	Min
GOLD THICKNESS4,000 Å	Min

CHIP THICKNESS.....10 Mils

TOLERANCES: ALL Dimensions ± 2 mils, Except Anode Pad Where Tolerance is \pm 0.5 mils.



COMPENSATED DEUICES INCORPORATED

22 COREY STREET, MELROSE, MASSACHUSETTS 02176 PHONE (781) 665-1071 WEBSITE: http://www.cdi-diodes.com

FAX (781) 665-7379 E-mail: mail@cdi-diodes.com

CD2810, CD5711, CD5712, CD6857, CD6858 and CD6916

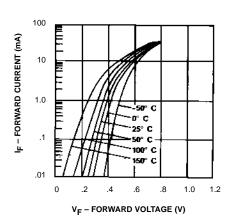
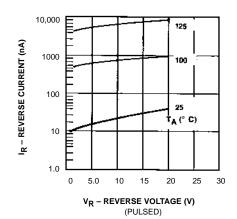


Figure 1.

I-V Curve Showing Typical Forward
Voltage Variation with Temperature for the
CD5712 and CD2810 Schottky Diodes.



 $\label{eq:Figure 2.} Figure 2. \\ CD5712 and CD2810 \\ Typical Variation of Reverse Current \\ (I_R) vs. Reverse Voltage (V_R) at Various Temperatures.$

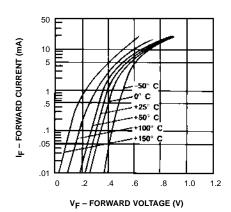


Figure 3.

I-V Curve Showing Typical Forward Voltage
Variation with Temperature for Schottky Diode
CD5711.

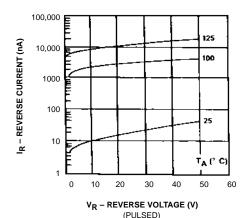
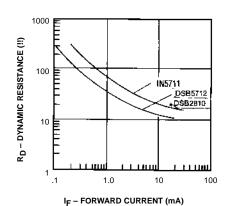


Figure 4. CD5711 Typical Variation of Reverse Current (I_R) vs. Reverse Voltage (V_R) at Various Temperatures.



(PULSED)